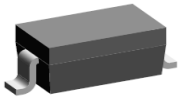
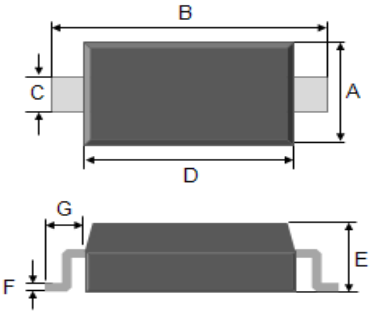
TAIWAN SEMICONDUCTOR

TESDC5V0LC
Bi-directional ESD Protection Diode

Small Signal Diode



SOD-323



Dimensions	Unit (mm)		Unit (inch)	
	Min	Max	Min	Max
A	1.20	1.40	0.047	0.055
B	2.50	2.70	0.098	0.106
C	0.25	0.35	0.010	0.014
D	1.60	1.80	0.063	0.071
E	0.80	0.90	0.031	0.035
F	0.08	0.15	0.003	0.006
G	0.19 REF		0.475 REF	

Features

- ✧Meet IEC61000-4-2 (ESD) ±15kV (air), ±8kV (contact)
- ✧Meet IEC61000-4-4 (EFT) rating. 40A (5/50ŋs)
- ✧Protects one birectional I/O line
- ✧Working Voltage : 5V
- ✧Pb free version, RoHS compliant, and Halogen free

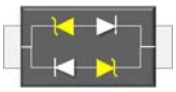
Mechanical Data

- ✧Case : SOD-323 small outline plastic package
- ✧Terminal: Matte tin plated, lead free., solderable per MIL-STD-202, Method 208 guaranteed
- ✧High temperature soldering guaranteed: 260°C/10s
- ✧Mounting position: Any
- ✧Weight : 4.85±0.5 mg
- ✧Marking Code : AC

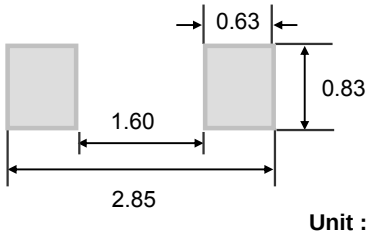
Applications

- ✧Cell Phone Handsets and Accessories
- ✧Notebooks, Desktops, and Servers
- ✧Keypads, Side Keys, USB 2.0, LCD Displays
- ✧Portable Instrumentation
- ✧Microprocessor based equipment

Pin Configutation



Suggested PAD Layout



Unit : mm

Ordering Information

Part No.	Package	Packing	Packing Code	Marking
TESDC5V0LC	SOD-323	3K / 7" Reel	RRG	AC

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Maximum Ratings

Type Number	Symbol	Value	Units
Peak Pulse Power (tp=8/20μs waveform)	P_{PP}	350	W
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V_{ESD}	±15 ±8	KV
Junction and Storage Temperature Range	T_J, T_{STG}	-55 to + 150	°C

Electrical Characteristics

Type Number			Symbol	Min	Max	Units
Reverse Stand-Off Voltage			V_{RWM}	-	5	V
Reverse Breakdown Volta	I_R=	1mA	$V_{(BR)}$	6	-	V
Reverse Leakage Curren	V_R=	5V	I_R	-	5	uA
Clamping Voltage	I_{PP}=	1A	Vc	-	9.8	V
	I_{PP}=	8A		-	18.3	
Junction Capacitance	V_R=0V, f=1.0MHz		C_J	1.2(Typ.)		pF

Notes: 1. The suggested land pattern dimensions have been provided for reference only, as actual pad layouts may vary despending on application.

Small Signal Diode

Rating and Characteristic Curves

FIG 1 Non-Repetitive Peak Pulse Power vs. Pulse Time

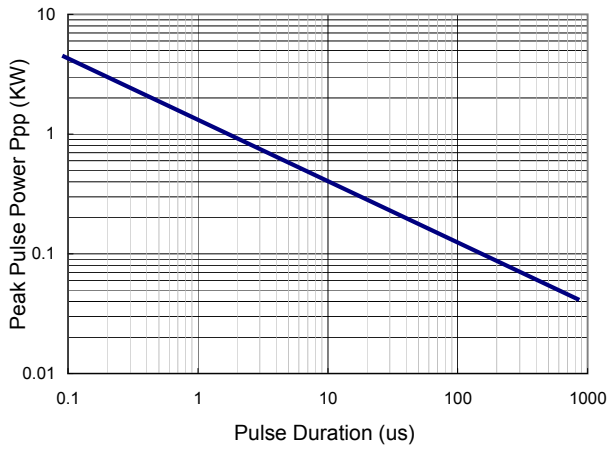


FIG 2 Pulse Waveform

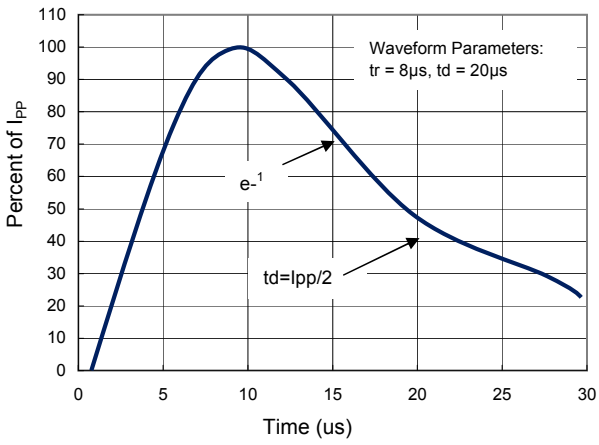


FIG 3 Admissible Power Dissipation Curve

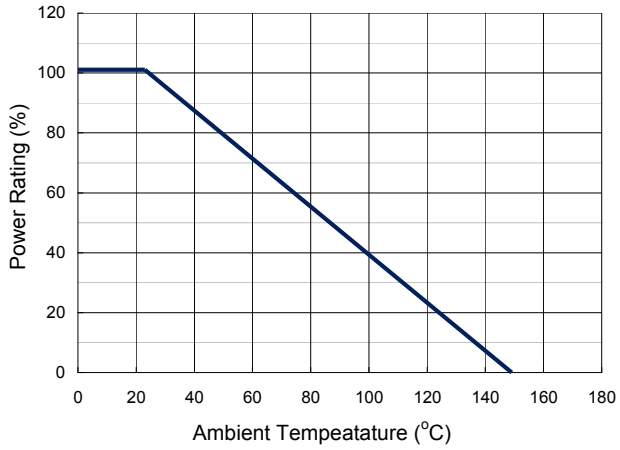


FIG 4 Typical Junction Capacitance

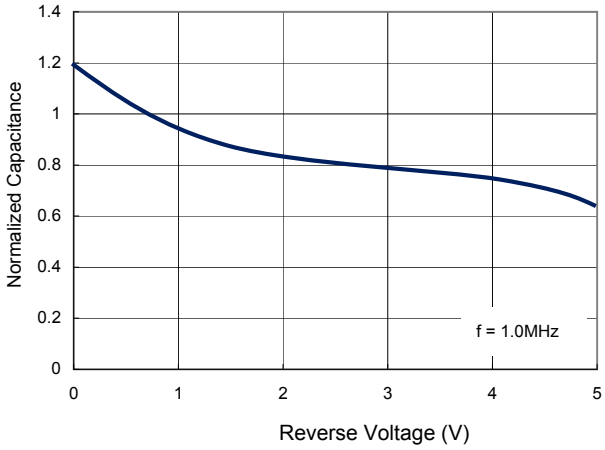
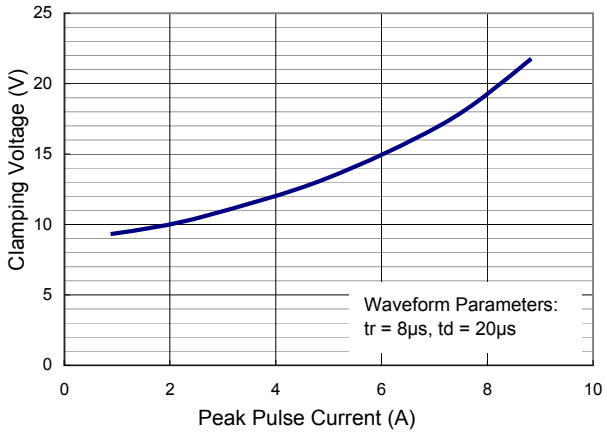


FIG 5 Clamping Voltage vs. Peak Pulse Current)



TAIWAN SEMICONDUCTOR

TESDC5V0LC
Bi-directional ESD Protection Diode

Small Signal Diode

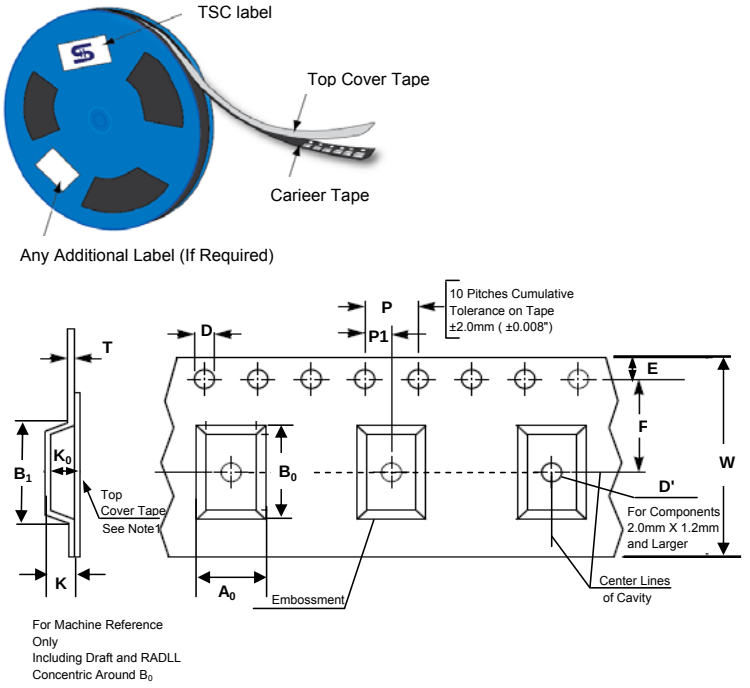
Applications Information

✧Designed to protect one data, I/O, or power supply line.
✧Designed to protect sensitive electronics from damage or latch-up due to ESD
✧Designed to replace multilayer varistors (MLVs) in portable applications
✧Offers superior electrical characteristics such as lower clamping voltage and no device degradation when compared to MLVs
✧The combination of small size and high ESD surge capability makes them ideal for use in portable applications.

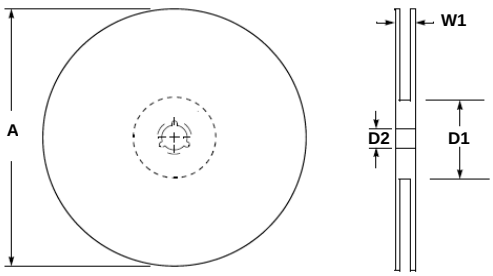
Circuit Board Layout Recommendations

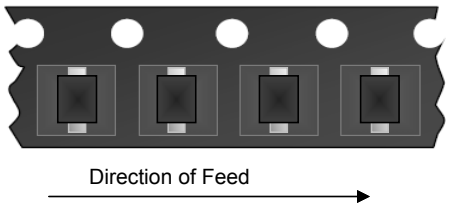
Good circuit board layout is critical for the suppression of ESD induced transients.
✧Place the ESD Protection Diode near the input terminals or connectors to restrict transient coupling.
✧Minimize the path length between the ESD Protection Diode and the protected line.
✧Minimize all conductive loops including power and ground loops.
✧The ESD transient return path to ground should be kept as short as possible.

Tape & Reel specification



Item	Symbol	Dimension (mm)
Carrier depth	K	2.40 Max.
Sprocket hole	D	1.50 +0.10
Reel outside diameter	A	178 ± 1
Reel inner diameter	D1	50 Min.
Feed hole width	D2	13.0 ± 0.5
Sprocke hole position	E	1.75 ±0.10
Punch hole position	F	3.50 ±0.05
Sprocke hole pitch	P0	4.00 ±0.10
Embossment center	P1	2.00 ±0.10
Overall tape thickness	T	0.6 Max.
Tape width	W	8.30 Max.
Reel width	W1	14.4 Max.





Note 1: A_0, B_0, and K_0 are determined by component size. The clearance between the components and the cavity must be within 0.05 mm min. to 0.5 mm max. The component cannot rote more than 10o within the determined cavity.
Note 2: If B1 exceeds 4.2 mm(0.165") for 8 mm embossed tape, the tape may not feed through all tape feeders.